

NPN Silicon Transistor

### **Descriptions**

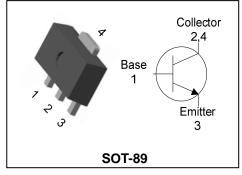
- General purpose amplifier
- High voltage application

### **Features**

- Low saturation switching application
- Voltage regulator application
- Low saturation: V<sub>CE</sub>(sat) = 0.4V typ
- High voltage : V<sub>CEO</sub>=60V Min

### **Ordering Information**

### **PIN Connection**



Type No.	Marking	Package Code
STC401F	C401 YWW	SOT-89

#### C401: DEVICE CODE, YWW(Y : Year code, WW : Weekly code)

#### Absolute maximum ratings

Absolute maximum ratings				
Characteristic	Symbol Ratings		Unit	
Collector-Base voltage	V <sub>CBO</sub>	80	V	
Collector-Emitter voltage	V <sub>CEO</sub>	60	V	
Emitter-base voltage	V <sub>EBO</sub>	5	V	
Collector current	Ι <sub>C</sub>	1	А	
Collector dissipation	Pc	0.5	14/	
	P <sub>C</sub> *	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55~150	°C	

Characteristic		Symbol	Тур.	Max	Unit
Thermal resistance	Junction-ambient	R <sub>th(J-A)</sub>	-	250.0	°C AM
		R <sub>th(J-A)</sub> *	-	125.0	°C/W

\*: When mounted on ceramic substrate(250 mm×0.8t)

## **Electrical Characteristics**

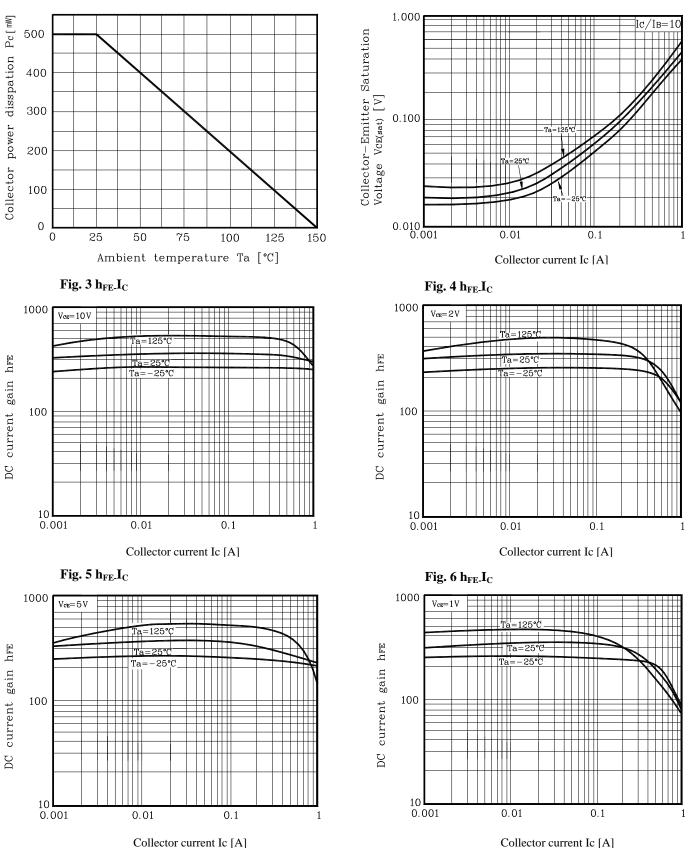
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = 100 \ \mu A$ , $I_{E} = 0$	80	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	60	-	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	$I_{E} = 10 \text{mA}, I_{C} = 0$	5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 60V, I_E = 0$	-	-	0.1	μΑ
Collector cut-off current	I <sub>CEO</sub>	$V_{CE} = 60V, I_B = 0$	-	-	0.5	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ =5V, $I_{C}$ =0	-	-	0.1	μΑ
DC current gain	h <sub>FE</sub> *	$V_{CE}$ =2V, $I_{C}$ =100mA	200	-	500	_
		$V_{CE}=2V$ , $I_{C}=1A$	80	-	-	
Base-Emitter on voltage	V <sub>BE(ON)</sub>	$V_{CE}$ =2V, $I_{C}$ =500mA	-	-	1.2	V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C}$ =500mA, $I_{B}$ =50mA	-	-	0.4	V
Collector output capacitance	C <sub>ob</sub>	$V_{CB}$ =10V, $I_E$ =0, f=1MHz	-	10	-	pF
Transition frequency	$f_{T}$	$V_{CB}$ =10V, $I_{C}$ =50mA	-	160	-	MHz

\* h<sub>FE</sub> rank : 200~500 Only

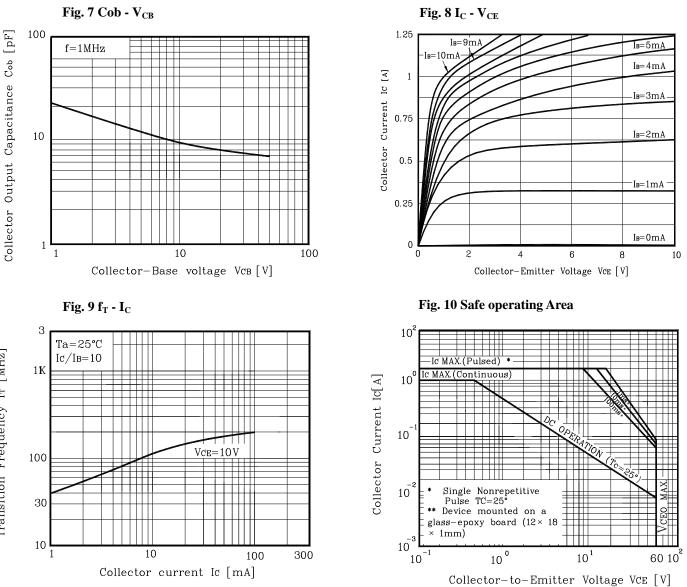
## **Electrical Characteristic Curves**



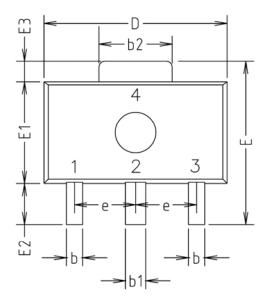
Fig. 2  $V_{CE}$  -  $I_C$ 

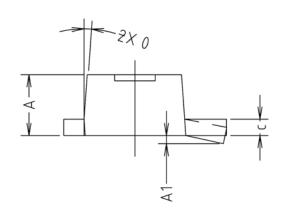


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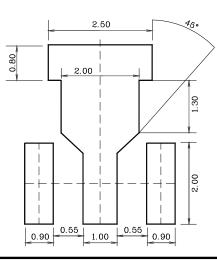
## **Outline Dimension(mm)**





		NOTE		
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	1.40	1.50	1.60	
A1	0.00	—	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
С	0.40	0.42	0.46	
D	4.40	4.50	4.70	
E	3.70	4.00	4.30	
E1	2.40	2.50	2.70	
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
е		1.50 TYP.		
θ		4° TYP.		

#### \* Recommend PCB solder land [Unit: mm]



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